TOSHIBA BIPOLAR LINEAR INTEGRATED CIRCUIT MULTI-CHIP

TA8486F

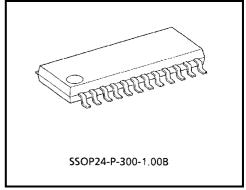
DRIVER FOR LOW-SATURATION VOLTAGE MOTORS

The TA8486F is a multi-chip IC containing ten low-saturation voltage discrete transistors.

The TA8486F is perfect as a driver for low–saturation driven motor drive transistors. 2.0 A is possible as the output current. Care must be taken over thermal conditions during usage.

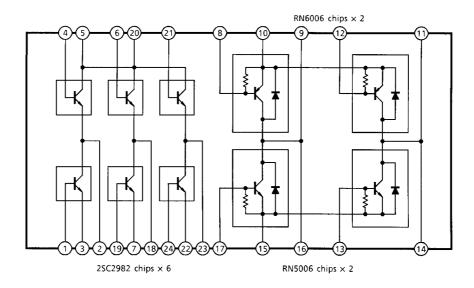
FEATURES

- Most suitable as a high-efficiency motor driver circuit
- Enclosed in a compact package: SSOP24.



Weight: 0.27 g (Typ.)

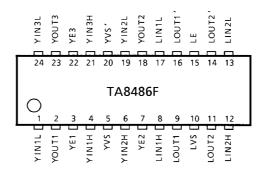
BLOCK DIAGRAM



Note: Short circuiting between output and line to ground faults may result in damage to the IC. Ensure that great care is taken during the design of the output line, V_{CC} (V_M, V_S, V_{EE}) and the GND line.

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PIN ASSIGNMENTS (TOP VIEW)



MAXIMUM RATINGS (Ta = 25°C)

H-bridge

CHARACTERISTIC	SYMBOL	RATING	UNIT	
Power Voltage	V _{CC}	10	V	
Voltage Between the Collector and Base	V _{CBO}	10	V	
Voltage Between the Collector and Emitter	V _{CER}	10	V	
Voltage Between the Emitter and Base	V _{EBO}	6	V	
Output Transistor Current	lout	2	Α	
Base Current	Ι _Β	±0.4	Α	
Diode Forward Current	I _F	2 (Note 1)	Α	
Power Dissipation	PD	830 (Note 2)	mW	
Connection Temperature	Tj	150	°C	
Operating Temperature	T _{opr}	-40~85	°C	
Storage Temperature	T _{stg}	-55~150	°C	

Note 1: T = 10 ms one-shot pulse

Note 2: Unit (package total)



Three-phase motor

CHARACTERISTIC	SYMBOL	RATING	UNIT	
Power Voltage	V _{CC}	15	V	
Voltage Between the Collector and Base	V _{CBO}	15	V	
Voltage Between the Collector and Emitter	V _{CER}	15	V	
Voltage Between the Emitter and Base	V _{EBO}	6	V	
Output Transistor Current	Io	2	Α	
Base Current	Ι _Β	0.4	Α	
Power Dissipation	PD	830 (Note 1)	mW	
Connection Temperature	Tj	150	°C	
Operating Temperature	T _{opr}	-40~85	°C	
Storage Temperature	T _{stg}	-55~150	°C	

Note 1: Unit (package total)

ELECTRICAL CHARACTERISTICS (Ta = 25°C)

H-bridge

CHARACTERISTICS		SYMBOL	TEST CIR- CUIT	TEST CONDITION	MIN	TYP.	MAX	UNIT
Direct Current Amplification		h _{FE (1)}	_	V_{CE} = 1 V, I_{C} = 0.5 A	160	_	600	_
		h _{FE (2)}	_	V _{CE} = 1 V, I _C = 2.0 A	60	130	_	
Output Saturation Voltage	Upper	VCE (sat)	_	$I_C = -1 \text{ A}, I_B = -25 \text{ mA}$	_	-0.15	-0.25	V
	Lower			I _C = 1 A, I _B = 25 mA	_	0.25	0.35	
	Upper and Lower			I _C = 1 A, I _B = 25 mA	_	0.4	0.6	
Transition Frequency		f _T	_	V _{CE} = 2 V, I _C = 0.5 A	_	150	_	MHz
Outrot Leals Ourse	Upper	l _{OL}	_	V _{CC} = −10 V	_	0	-5	μA
Output Leak Current	Lower			V _{CC} = 10 V	_	0	5	
Diode Forward Voltage	Upper	V _F	_	I _F = 300 mA	_	1.1	1.3	V
	Lower			I _F = 300 mA	_	1.1	1.3	
Resistance Between the Base and Emitter		R _{BE}	_	-	7	10	13	kΩ
Voltage Between the Base and Emitter		V _{BE} (PNP)	_	$V_{CE} = -1 \text{ V, } I_{C} = -2 \text{ A}$	_	-0.84	-1.5	V
		V _{BE (NPN)}	_	V _{CE} = 1 V, 1 _C = 2 A	_	0.84	1.5	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \

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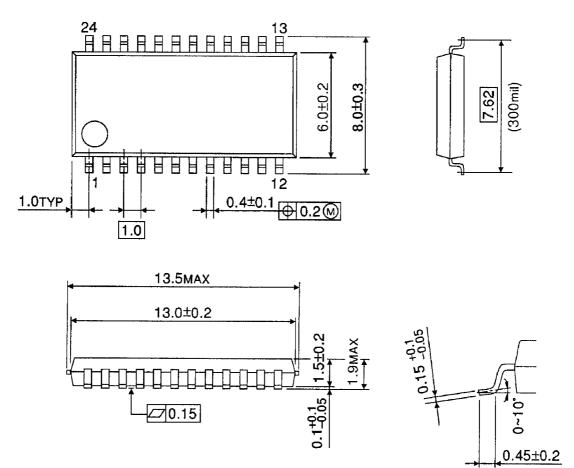


Three-phase motor

CHARACTERISTICS		SYMBOL	TEST CIR- CUIT	TEST CONDITION	MIN	TYP.	MAX	UNIT
Direct Current Amplification		h _{FE (1)}	_	V _{CE} = 0.4 V, I _C = 30 mA	160	_	600	_
		h _{FE (2)}	_	V _{CE} = 0.4 V, I _C = 0.2 A	160	_	600	
h _{FE} Ratio		h _{FE (1)} / h _{FE (2)}	_	V _{CE} = 0.4 V, I _C = 30 mA / V _{CE} = 0.4 V, I _C = 0.2 A	0.75	_	1.25	_
Output Saturation Voltage	Upper	VCE (sat)	_	I _C = 1 A, I _B = 25 mA	_	0.2	0.35	V
	Lower			I _C = 1 A, I _B = 25 mA	_	0.2	0.35	
	Upper and Lower			I _C = 1 A, I _B = 25 mA	_	0.4	0.7	
Transition Frequency		f _T	_	V _{CE} = 2 V, I _C = 0.5 A	_	140	_	MHz
Output Leak Current	Upper	l _{OL} –	_	V _{CC} = 15 V	_	0	10	μА
	Lower			V _{CC} = 15 V	_	0	10	
Voltage Between the Base and Emitter		V _{BE} (NPN)	_	V _{CE} = 1 V, I _C = 2 A		0.84	1.5	V

PACKAGE DIMENSIONS

SSOP24-P-300-1.00B Unit: mm



Weight: 0.27 g (Typ.)

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